



# **RFLM-300301QC-290**

## **Quasi Active High Power VHF Band Limiter Module**

### **Features:**

- Frequency Range: 30 to 300 MHz
- High Average Power Handling: +56 dBm
- High Peak Power Handling: +56 dBm
- Low Insertion Loss: 0.7 dB
- Return Loss: 15 dB
- Low Flat Leakage Power: 19 dBm
- SMT Module: 8mm x 5mm x 2.5mm
- DC Coupling Capacitors
- No external control lines or power supply required
- RoHS Compliant

### **Description:**

The RFLM-300301QC-290 SMT Silicon PIN Diode Limiter Module offers both High Power CW and Peak protection in the VHF Band region. It is based on a proven hybrid assembly technique utilized extensively in high reliability, mission critical applications. The RFLM-300301QC-290 offers excellent thermal characteristics in a compact, low profile 8mm x 5mm x 2.5mm package. The RFLM-300301QC-290 is designed for optimal small signal insertion loss permitting extremely low receiver noise figure while simultaneously offering excellent large input signal Flat Leakage for effective receiver protection in the UHF Band frequency range.

The limiter RF circuit characteristics provide outstanding passive receiver protection (Always On) which protects against High Average Power up to +56 dBm, High Peak Power up to +56 dBm pulsed, and maintains low Flat Leakage to less than 19 dBm.

### **ESD and Moisture Sensitivity Rating**

The RFLM300301QC-290 Limiter Module carries a Class 0 ESD rating (HBM) and an MSL 1 moisture rating.

### **Thermal Management Features**

The RFLM-300301QC-290 based substrate has been design to offer superior long term reliability in the customer's application by utilizing ultra-thin Au plating to combat Au embrittlement concerns. Also, a proprietary design methodology has minimized the thermal resistance from the PIN Diode junction to base plate. The two stage limiter design employs a second stage Schottky and quarter wavelength spacer detector circuit which permits ultra-fast turn on of the High Power PIN Diodes. This circuit topology coupled with the thermal

characteristic of the substrate design enables reliably handling High Input RF Power up to +56 dBm CW and RF Peak Power levels up to +56 dBm (30 ms pulse width @ 20% duty cycle with base plate temperature at 75°C).

## Absolute Maximum Ratings

@  $Z_0=50\Omega$ ,  $T_A=+25^\circ\text{C}$  as measured on the base ground surface of the device.

Parameter	Conditions	Absolute Maximum Value
Operating Temperature		-65°C to 125°C
Storage Temperature		-65°C to 150°C
Junction Temperature		175°C
Assembly Temperature	T = 30 seconds	260°C
RF Peak Incident Power	$T_{\text{CASE}}=75^\circ\text{C}$ , source and load VSWR < 1.2, RF Pulse width = 30 msec, duty cycle = 20%, derated linearly to 0 W at $T_{\text{CASE}}=150^\circ\text{C}$ (See note 1)	+56 dBm
RF CW Incident Power		+56 dBm
RF Input & Output DC Block Capacitor Voltage Breakdown		100 V DC

Note 1:  $T_{\text{CASE}}$  is defined as the temperature of the bottom ground surface of the device.

## RFLM300301QC-290 Electrical Specifications

@  $Z_0=50\Omega$ ,  $T_A=+25^\circ\text{C}$  as measured on the base ground surface of the device.

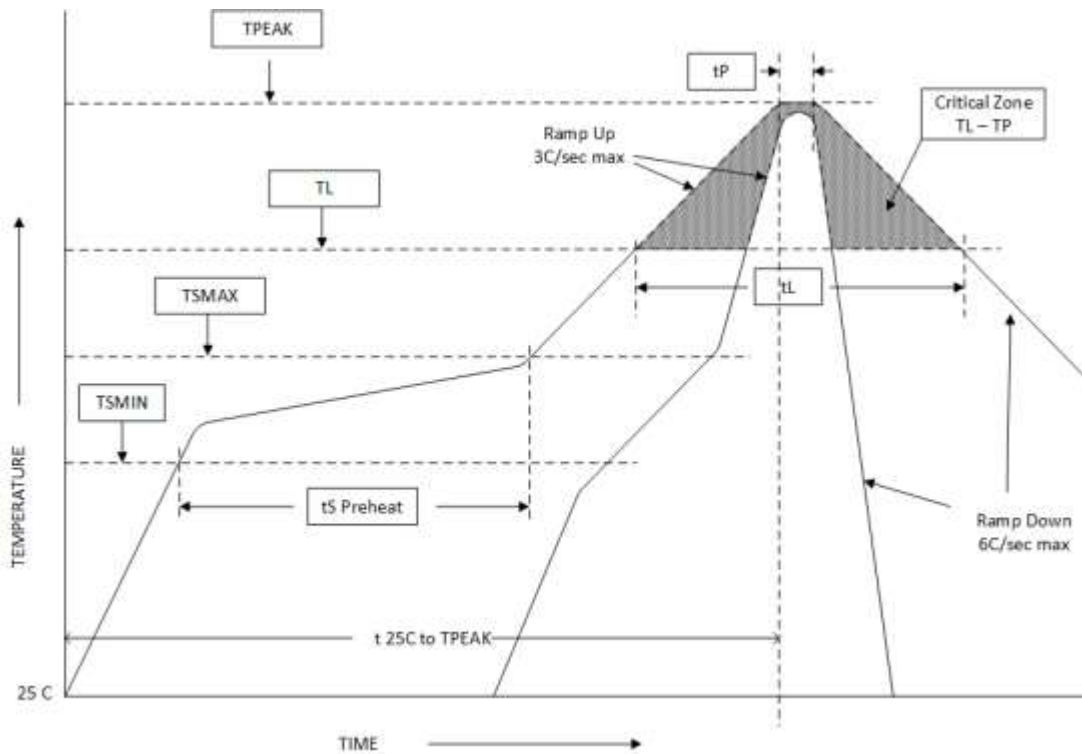
Parameters	Symbol	Test Conditions	Min Value	Typ Value	Max Value	Units
Frequency	F	30 MHz $\leq$ F $\leq$ 300 MHz	30		300	MHz
Insertion Loss	IL	$P_{\text{in}} = -20$ dBm, F = 30 – 300 MHz		0.3	0.7	dB
Insertion Loss Rate of Change vs Operating Temperature	$\Delta\text{IL}$	300 MHz $\leq$ F $\leq$ 512 MHz, $P_{\text{in}} \leq -20$ dBm		0.005		dB/°C
Return Loss	RL	$P_{\text{in}} = -20$ dBm, F = 30 - 300 MHz		22	15	dB
Input 1 dB Compression Point	$\text{IP}_{1\text{dB}}$	30 MHz $\leq$ F $\leq$ 300 MHz		12		dBm
2 <sup>nd</sup> Harmonic	$2F_o$	$P_{\text{in}} = 0$ dBm, $F_o = 300$ MHz		-45		dBc
Peak Incident Power	$P_{\text{inc(PK)}}$	RF Pulse = 30 msec, duty cycle = 20%, $t_{\text{rise}} \leq 2\mu\text{s}$ , $t_{\text{fall}} \leq 2$ usec			56	dBm
CW Incident Power	$P_{\text{inc(CW)}}$	30 MHz $\leq$ F $\leq$ 300 MHz			56	dBm
Flat Leakage	FL	$P_{\text{in}} = 56$ dBm, RF Pulse width = 30 ms, duty cycle = 20%, $t_{\text{rise}} \leq 2$ us, $t_{\text{fall}} \leq 2$ us		19		dBm
Spike Leakage Power	SLP	$P_{\text{in}} = 56$ dBm, RF Pulse width = 30 ms, duty cycle = 20%		28		dBm
Spike Leakage Energy	SLE	$P_{\text{in}} = 56$ dBm, RF Pulse width = 30 ms, duty cycle = 20%		0.5		erg
Recovery Time	$T_R$	50% falling edge of RF Pulse to 1 dB IL, $P_{\text{in}} = 56$ dBm peak, RF PW = 30 ms, duty cycle = 20%, $t_{\text{rise}} \leq$ 2us, $t_{\text{fall}} \leq 1$ usec		7.5		usec

## Assembly Instructions

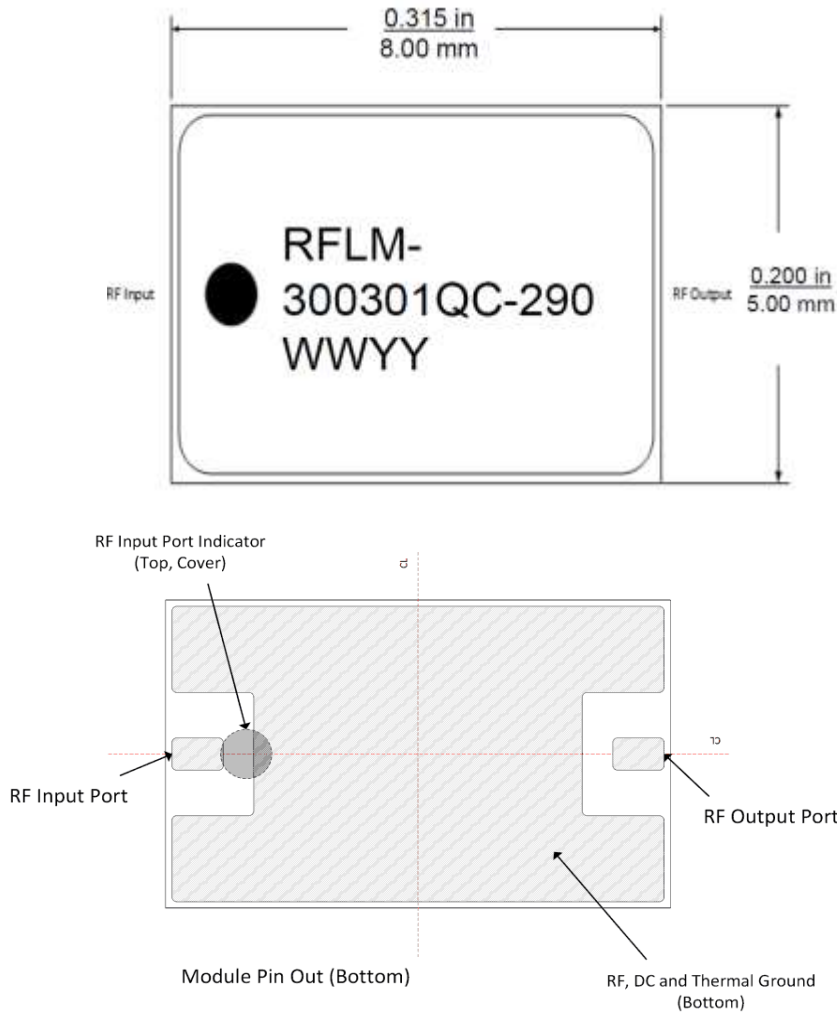
The RFLM-300301QC-290 may be attached to the printed circuit card using solder reflow procedures using either RoHS or Sn63/ Pb37 type solders per the Table and Temperature Profile Graph shown below:

Profile Parameter	Sn-Pb Assembly Technique	RoHS Assembly Technique
Average ramp-up rate ( $T_L$ to $T_P$ )	3°C/sec (max)	3°C/sec (max)
Preheat		
Temp Min ( $T_{smin}$ )	100°C	100°C
Temp Max ( $T_{smax}$ )	150°C	150°C
Time (min to max) ( $t_s$ )	60 – 120 sec	60 – 120 sec
$T_{smax}$ to $T_L$		
Ramp up Rate		3°C/sec (max)
Peak Temp ( $T_P$ )	225°C +0°C / -5°C	260°C +0°C / -5°C
Time within 5°C of Actual Peak Temp ( $T_P$ )	10 to 30 sec	20 to 40 sec
Time Maintained Above:		
Temp ( $T_L$ )	183°C	217°C
Time ( $t_L$ )	60 to 150 sec	60 to 150 sec
Ramp Down Rate	6°C/sec (max)	6°C/sec (max)
Time 25°C to $T_P$	6 minutes (max)	8 minutes (max)

## Solder Re-Flow Time-Temperature Profile



## RFLM-300301QC-290 Limiter Module Package Outline Drawing



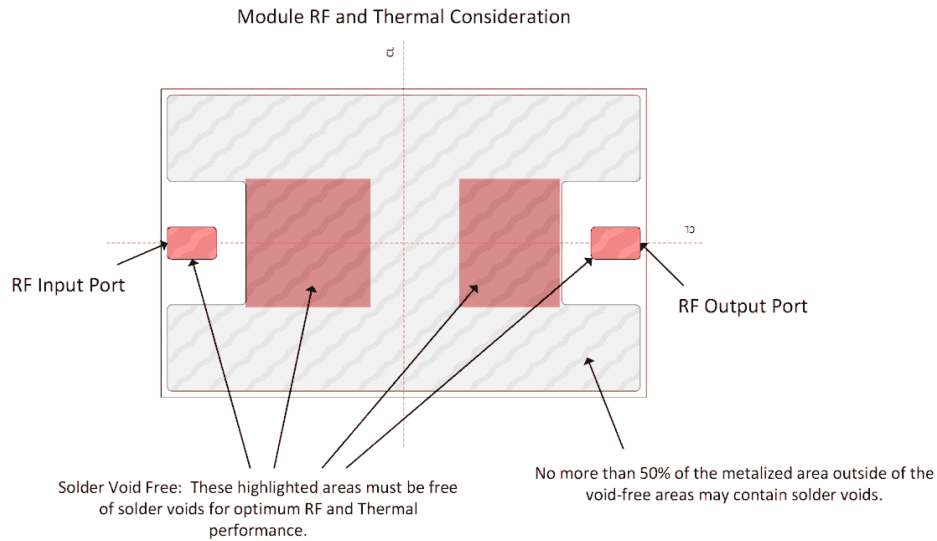
**Notes:**

- 1) Metalized area on backside is the RF, DC and Thermal ground. In user's end application this surface temperature must be managed to meet the power handling requirements.
- 2) Back side metallization is thin Au termination plating to combat Au embrittlement (Au plated over Cu).

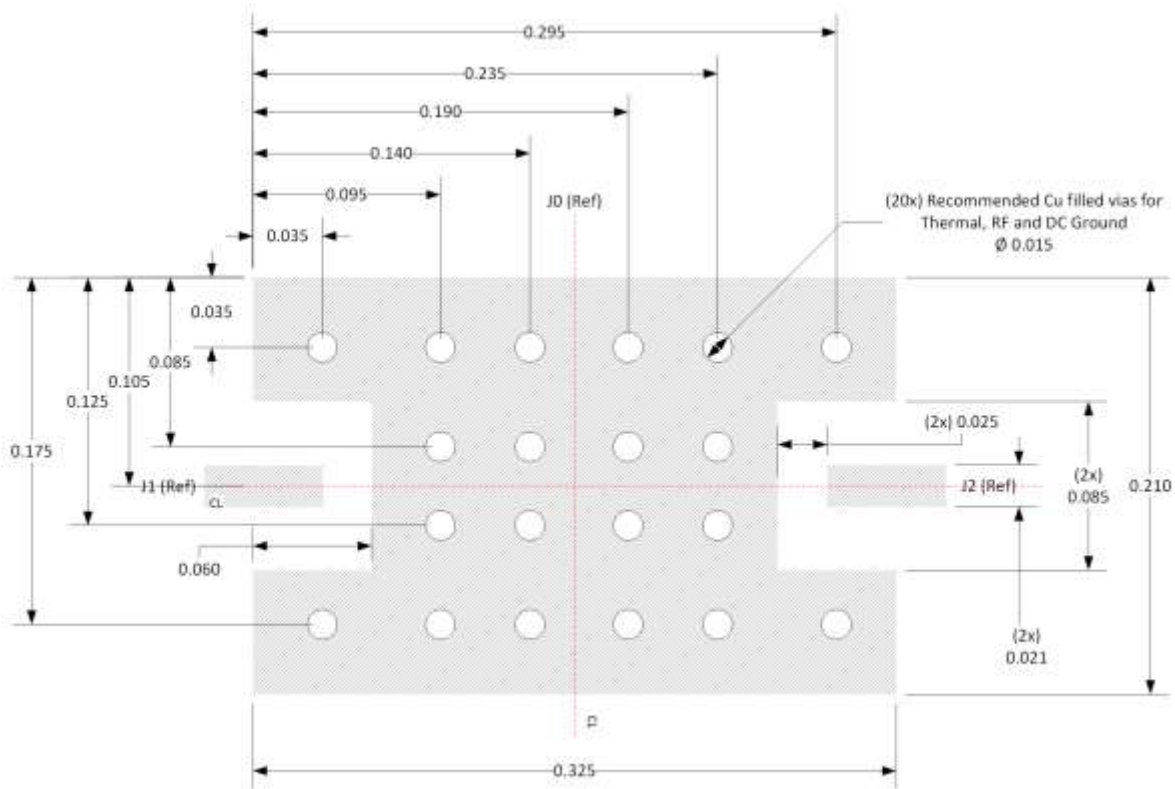
### Thermal Design Considerations:

The design of the RFLM-300301QC-290 Limiter Module permits the maximum efficiency in thermal management of the PIN Diodes while maintaining extremely high reliability. Optimum Limiter performance and reliability of the device can be achieved by the maintaining the base ground surface temperature of less than 85°C.

There must be a minimal thermal and electrical resistance between the limiter bottom surface and ground. Adequate thermal management is required to maintain a  $T_{JC}$  at less than  $+175^{\circ}\text{C}$  and thereby avoid adversely affecting the semiconductor reliability. Special care must be taken to assure that minimal voiding occurs in the solder connection in the area shaded in red in the figure shown below:



### Recommended RF Circuit Solder Footprint for the RFLM300301QC-290



Notes:

- 1) Recommended PCB material is Rogers 4350B, 20 mils thick (RF Input and Output trace width needs to be adjusted from the recommended footprint.)
- 2) Foot print is suggested for low level signal application. High power applications require device to be mounted directly to an adequate heat. Please contact the factory for assistance.
- 3) Hatched area is RF, DC and Thermal Ground.

**Part Number Ordering Detail:**

The RFLM-300301QC-290 Limiter Module is available in the following format:

<b>Part Number</b>	<b>Description</b>	<b>Packaging</b>
RFLM-300301QC-290	VHF Band Limiter, Input & Output Blocking Caps	Gel-Pack